



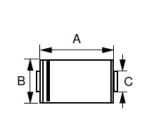
LITE-ON SEMICONDUCTOR ES3G(LS)

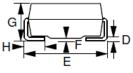
SURFACE MOUNT **REVERSE VOLTAGE – 400 Volts** SUPER FAST RECTIFIERS FORWARD CURRENT – 3.0 Ampere **FEATURES** SMC · Glass passivated chip · Super fast switching for high efficiency

- · For surface mounted applications
- · Low forward voltage drop and high current capability
- · Low reverse leakage current
- Available in "Green" Package: SMC
 - Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
 - Halogen and Antimony Free. "Green" Device (Note 3)

MECHANICAL DATA

- · Case: Molded plastic
- · Case Material: Molding compound, UL Flammability classification 94V-0,"Halogen-free".
- · Polarity: Color band denotes cathode
- Weight: 0.021 grams





| SMC | | | | |
|-----------------------------|---------|------|--|--|
| DIM | MIN MAX | | | |
| А | 6.60 | 7.11 | | |
| В | 5.59 | 6.22 | | |
| С | 2.92 | 3.18 | | |
| D | 0.15 | 0.31 | | |
| Е | 7.75 | 8.13 | | |
| F | 0.05 | 0.20 | | |
| G | 2.01 | 2.50 | | |
| Н | 0.76 | 1.52 | | |
| All dimension in millimeter | | | | |

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

| PARAMETER | | SYMBOL | ES3G | UNIT |
|--|-------------------------|-------------------|-----------------|------------------|
| Maximum Repetitive Peak Reverse Voltage | | V _{RRM} | 400 | V |
| Maximum RMS Voltage | | V _{RMS} | 280 | V |
| Maximum DC Blocking Voltage | | V _{DC} | 400 | V |
| Maximum Average Forward Rectified Current | @T _L =110°C | I _(AV) | 3.0 | А |
| Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load (JEDEC METHOD) | | I _{FSM} | 100 | А |
| Peak Forward Surge Current 1ms single half sine-wave | @ T _J =25°C | I _{FSM} | 200 | А |
| 2 t Rating for fusing (3ms \leq t \leq 8.3ms) | | l ² t | 41.5 | A ² S |
| Maximum forward Voltage at 3.0A DC | | VF | 1.25 | V |
| Maximum DC Reverse Current at Rated DC Blocking Voltage | @ T」=25°C @ T」=125°C | I _R | 10 500 | uA |
| Maximum Reverse Recovery Time (Note 4) | | t _{rr} | 25 20 (Typ.) | ns |
| Typical Junction Capacitance (Note 5) | | Ст | 45 | pF |
| Typical Thermal Resistance (Note 6) | | R _{thJL} | 10 | *CAM |
| | | R _{thJA} | 50 | •C/W |
| Operating Temperature Range | | TJ | -55 to + 150 | °C |
| Storage Temperature Range | | T _{STG} | -55 to + 150 | °C |

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony

compounds.

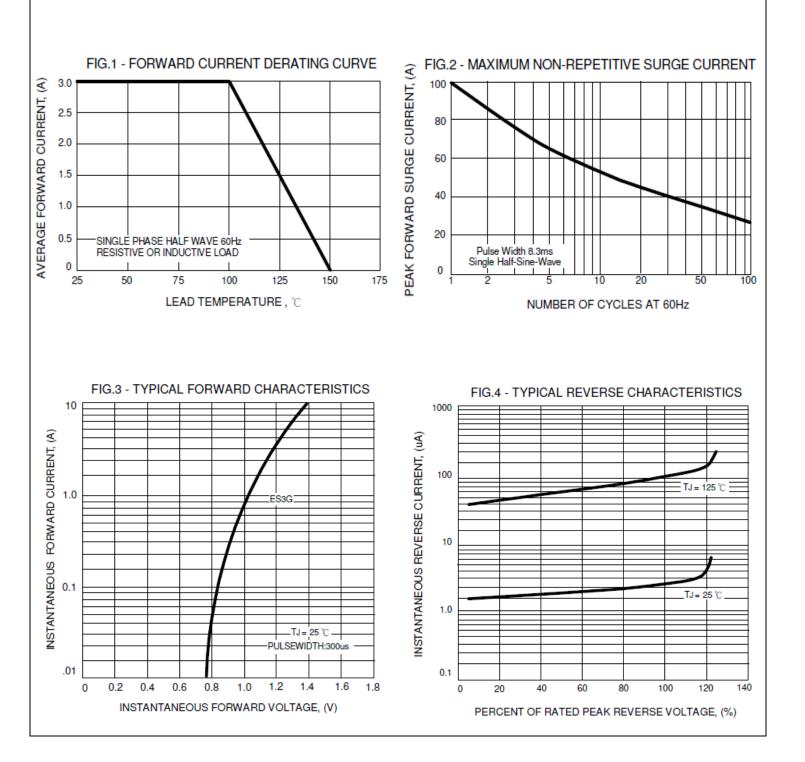
4. Reverse Recovery Test Conditions :I_F=0.5A,I_R=1.0A,I_{rr}=0.25A.

5. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

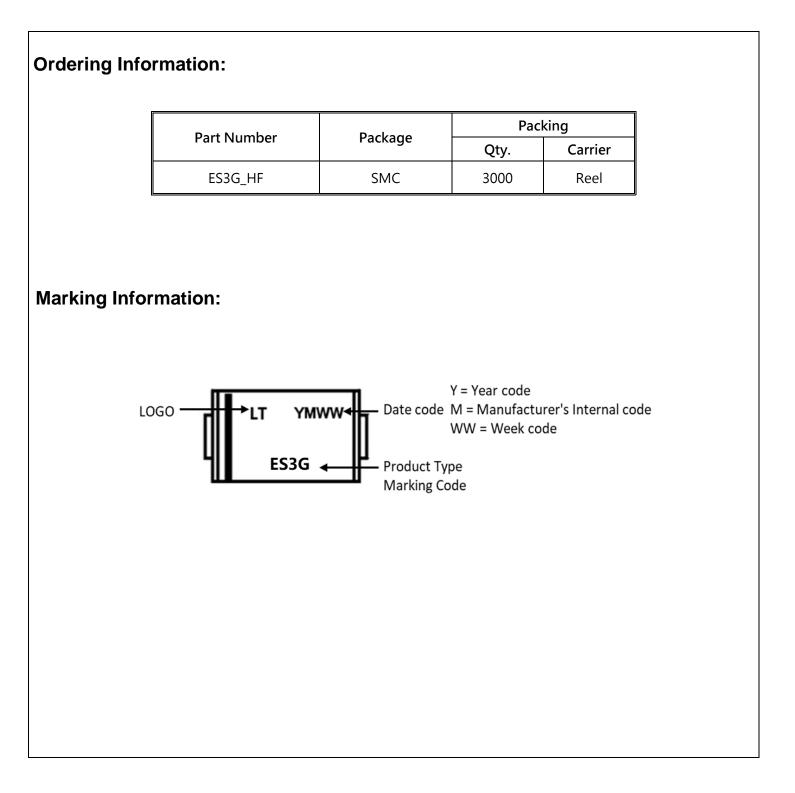
6. Thermal Resistance junction to Lead and Ambient.



LITE-ON SEMICONDUCTOR









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